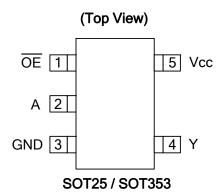


Description

The 74AHC1G125 is a single non-inverting buffer/bus driver with a 3-state output. The output enters a high impedance state when a HIGH-level is applied to the output enable (\overline{OE}) pin. The device is designed for operation with a power supply range of 2.0V to 5.5V.

Pin Assignments



Features

- Supply Voltage Range from 2.0V to 5.5V
- ± 8 mA Output Drive at 5.0V
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time.
- ESD Protection per JESD 22
 - o Exceeds 200-V Machine Model (A115-A)
 - o Exceeds 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- SOT25 and SOT353: Assembled with "Green" Molding Compound (no Br, Sb)
- Lead Free Finish / RoHS Compliant (Note 1)

Applications

- General Purpose Logic
- Wide array of products such as:
 - o PCs, networking, notebooks, netbooks, PDAs
 - o Computer peripherals, hard drives, CD/DVD ROM
 - o TV, DVD, DVR, set top box
 - Phones, Personal Navigation / GPS
 - o MP3 players ,Cameras, Video Recorders

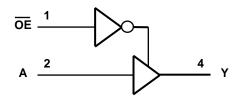
Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html.



Pin Descriptions

| Pin Name | Pin No. | Description |
|----------|---------|----------------|
| ŌE | 1 | Output Enable |
| А | 2 | Data Input |
| GND | 3 | Ground |
| Y | 4 | Data Output |
| Vcc | 5 | Supply Voltage |

Logic Diagram



Function Table

| Inp | Output | |
|-----|--------|---|
| OE | Α | Υ |
| L | Н | Н |
| L | L | L |
| Н | X | Z |



Absolute Maximum Ratings (Note 2)

| Symbol | Description | Rating | Unit |
|------------------|--|------------------------------|------|
| ESD HBM | Human Body Model ESD Protection | 2 | KV |
| ESD CDM | Charged Device Model ESD Protection | 1 | K۷ |
| ESD MM | Machine Model ESD Protection | 200 | V |
| V _{CC} | Supply Voltage Range | -0.5 to 6.5 | V |
| VI | Input Voltage Range | -0.5 to 6.5 | V |
| Vo | Voltage applied to output in high or low state | -0.5 to V _{CC} +0.5 | V |
| I _{IK} | Input Clamp Current V _I <0 | -20 | mA |
| l _{OK} | Output Clamp Current (V _O < 0 or V _O > V _{CC}) | ±20 | mA |
| I _O | Continuous output current (V _O = 0 to V _{CC}) | ±25 | mA |
| I _{CC} | Continuous current through V _{CC} | 50 | mA |
| I _{GND} | Continuous current through GND | -50 | mA |
| TJ | Operating Junction Temperature | -40 to 150 | °C |
| T _{STG} | Storage Temperature | -65 to 150 | °C |

Notes: 2. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 3)

| Symbol | | Parameter | Min | Max | Unit |
|-----------------|--------------------------------|--------------------------|------|-----------------|-------|
| V _{CC} | Operating Voltage | | 2 | 5.5 | V |
| | | V _{CC} = 2V | 1.5 | | |
| V_{IH} | High-level Input Voltage | $V_{CC} = 3V$ | 2.1 | | V |
| | | $V_{CC} = 5.5V$ | 3.85 | | |
| | | $V_{CC} = 2V$ | | 0.5 | |
| V_{IL} | Low-level input voltage | $V_{CC} = 3V$ | | 0.9 | V |
| | | V _{CC} = 5.5V | | 1.65 | |
| VI | Input Voltage | | 0 | 5.5 | V |
| Vo | Output Voltage | | 0 | V _{CC} | V |
| | | V _{CC} = 2V | | -50 | uA |
| I _{OH} | High-level output current | $V_{CC} = 3.3V \pm 0.3V$ | | -4 | A |
| | | $V_{CC} = 5V \pm 0.5V$ | | -8 | mA mA |
| | | V _{CC} = 2V | | 50 | uA |
| I_{OL} | Low-level output current | $V_{CC} = 5V \pm 0.5V$ | | 4 | 0 |
| | | $V_{CC} = 3V$ | | 8 | mA mA |
| A (/ A) / | Input transition rise or fall | $V_{CC} = 3.3V \pm 0.3V$ | | 100 | 0.7 |
| Δt/ΔV | rate | $V_{CC} = 5V \pm 0.5V$ | | 20 | ns/V |
| T _A | Operating free-air temperature | | -40 | 125 | °C |

Notes: 3. Unused inputs should be held at V_{CC} or Ground.



Electrical Characteristics

| 0 | 5 | T | W | | 25°C | | -40°C t | o 85°C | -40°C to | o 125ºC | 11.24 |
|-----------------|---|-----------------------------|-----------------|------|------|-------|---------|--------|----------|---------|-------|
| Symbol | Parameter | Test Conditions | V _{CC} | Min | Тур. | Max | Min | Max | Min | Max | Unit |
| | | | 2V | 1.9 | 2 | | 1.9 | | 1.9 | | |
| | | $I_{OH} = -50\mu A$ | 3V | 2.9 | 3 | | 2.9 | | 2.9 | | |
| V _{OH} | High Level | | 4.5V | 4.4 | 4.5 | | 4.4 | | 4.4 | | V |
| | Output Voltage | $I_{OH} = -4mA$ | 3V | 2.58 | | | 2.48 | | 2.40 | | |
| | | I _{OH} = -8mA | 4.5V | 3.94 | | | 3.8 | | 3.70 | | |
| | | | 2V | | | 0.1 | | 0.1 | | 0.1 | |
| | | $I_{OL} = 50\mu A$ | 3V | | | 0.1 | | 0.1 | | 0.1 | |
| V _{OL} | Low Level | | 4.5V | | | 0.1 | | 0.1 | | 0.1 | V |
| | Output Voltage | I _{OL} = 4mA | 3V | | | 0.36 | | 0.44 | | 0.55 | |
| | | $I_{OL} = 8mA$ | 4.5V | | | 0.36 | | 0.44 | | 0.55 | |
| II | Input Current | $V_I = 5.5V$ or GND | 0 to 5.5V | | | ± 0.1 | | ± 1 | | ± 2 | μΑ |
| I _{OZ} | Z State Leakage Current | V _O =0 to 5.5V | 5.5V | | | 0.25 | | 2.5 | | 10 | μΑ |
| I _{CC} | Supply Current | $V_I = 5.5V$ or GND $I_O=0$ | 5.5V | | | 1 | | 10 | | 40 | μΑ |
| C _i | Input Capacitance | $V_I = V_{CC} - or$ GND | 5.5V | | 2.0 | 10 | | 10 | | 10 | pF |
| | Thermal Resistance | SOT25 | (Note 4) | | 195 | | | | | | °C/W |
| θ _{JA} | Junction-to- Ambient | SOT353 | (Note 4) | | 430 | | | | | | C/VV |
| | Thermal Resistance Junction-to- Case | SOT25 | (Note 4) | | 58 | | | | | | °C/W |
| θ _{JC} | | SOT353 | (Note 4) | | 155 | | | | | | C/VV |

Note: 4. Test conditions for SOT25, and SOT353: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



Switching Characteristics

 $V_{CC} = 3.3V \pm 0.3$ (see Figure 1)

| Parameter | From | | то | | 25ºC | | -40°C t | o 85ºC | -40°C to | o 125ºC | Unit |
|------------------|---------|-------------|----------------------|-----|------|------|---------|--------|----------|---------|-------|
| Parameter | (Input) | (OUTPUT) | | Min | Тур. | Max | Min | Max | Min | Max | Offic |
| 4 | ^ | > | C _L =15pF | 0.6 | 4.7 | 8.0 | 0.6 | 9.5 | 0.6 | 11.5 | ns |
| t _{pd} | Α | ĭ | C _L =50pF | 0.6 | 6.6 | 11.5 | 0.6 | 13.0 | 0.6 | 14.5 | ns |
| 4 | | V | C _L =15pF | 0.6 | 5.0 | 8.0 | 0.6 | 9.5 | 0.6 | 10.5 | ns |
| t _{en} | OE | ĭ | C _L =50pF | 0.6 | 6.9 | 11.5 | 0.6 | 13.0 | 0.6 | 14.5 | ns |
| 4 | OE | V | C _L =15pF | 0.6 | 6.0 | 9.7 | 0.6 | 11.5 | 0.6 | 12.5 | ns |
| t _{dis} |) D | Ĭ | C _L =50pF | 0.6 | 8.3 | 13.2 | 0.6 | 15.0 | 0.6 | 16.5 | ns |

$V_{CC} = 5V \pm 0.5V$ (see Figure 1)

| Doromotor | From | om TO | | | 25°C | | -40°C to 85°C | | -40°C to 125°C | | Unit |
|------------------|---------|----------|----------------------|-----|------|------|---------------|------|----------------|------|------|
| Parameter | (Input) | (OUTPUT) | | Min | Тур. | Max | Min | Max | Min | Max | Unit |
| | ^ | V | C _L =15pF | 0.6 | 3.4 | 5.5 | 0.6 | 6.5 | 0.6 | 7.0 | ns |
| t _{pd} | Α | Ť | C _L =50pF | 0.6 | 4.8 | 7.5 | 0.6 | 8.5 | 0.6 | 9.5 | ns |
| | | V | C _L =15pF | 0.6 | 3.6 | 5.1 | 0.6 | 6.0 | 0.6 | 6.5 | ns |
| t _{en} | OE | Ť | C _L =50pF | 0.6 | 6.5 | 11.4 | 0.6 | 13.0 | 0.6 | 14.5 | ns |
| 4 | ŌE | JE V | C _L =15pF | 0.6 | 4.1 | 6.8 | 0.6 | 8.0 | 0.6 | 8.5 | ns |
| t _{dis} | OE | Ť | C _L =50pF | 0.6 | 5.7 | 8.8 | 0.6 | 10.0 | 0.6 | 11.0 | ns |

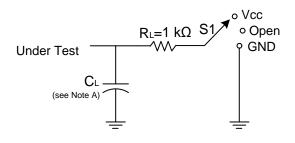
Operating Characteristics

 $T_A = 25$ °C

| | Parameter | Test Conditions | V _{CC} = 5 V Typ. | Unit |
|--------------|-------------------------------|----------------------|-------------------------------|------|
| $C_{\sf pd}$ | Power dissipation capacitance | f = 1 MHz No Load | 12 | pF |

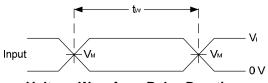


Parameter Measurement Information

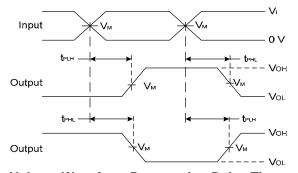


| TEST | S1 |
|------------------------------------|-----------|
| t _{PLH} /t _{PHL} | Open |
| t _{PLZ} /t _{PZL} | Vload |
| t _{PHZ} /t _{PZH} | GND |

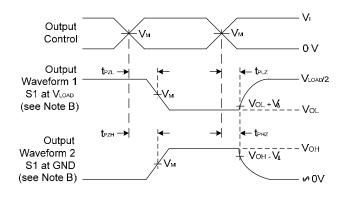
| V | Inputs | | V | 0 | V. |
|-----------------|-----------------|--------------------------------|--------------------|------|------------|
| V _{CC} | VI | t _r /t _f | V _M | CL | V Δ |
| 3.3V±0.3V | V _{CC} | ≤3ns | V _{CC} /2 | 15pF | 0.3V |
| 5V±0.5V | V _{CC} | ≤3ns | V _{CC} /2 | 15pF | 0.3V |
| 3.3V±0.3V | V _{CC} | ≤3ns | V _{CC} /2 | 50pF | 0.3V |
| 5V±0.5V | V _{CC} | ≤3ns | V _{CC} /2 | 50pF | 0.3V |



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs



Voltage Waveform Enable and Disable Times
Low and High Level Enabling

Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 1 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLZ} and t_{PHZ} are the same as t_{dis.}
- E. t_{PZL} and t_{PZH} are the same as t_{EN}.
- F. t_{PLH} and t_{PHL} are the same as t_{PD.}

(B) (B)



SINGLE BUFFER GATE WITH 3-STATE OUTPUT

Ordering Information

T4 AHC1G 125 XX - 7

Logic Device Function Package Packing

74 : Logic Prefix 125 : 3-State Buffer W5 : SOT25 7 : Tape & Reel

OE-Low

SE: SOT353

AHC: 2 to 5.5V Family 1G: One gate

| Davies | Package | Packaging | 7" Tape | and Reel |
|----------------|---------|-----------|------------------|--------------------|
| Device | Code | (Note 5) | Quantity | Part Number Suffix |
| 74AHC1G125W5-7 | W5 | SOT25 | 3000/Tape & Reel | -7 |
| 74AHC1G125SE-7 | SE | SOT353 | 3000/Tape & Reel | -7 |

Notes: 5. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

Marking Information

(Top View)

 $\underline{XX} \ \underline{Y} \ \underline{W} \ \underline{X}$ W: Week: A~Z: 1~26 week; a~z: 27~52 week; z represents 52 and 53 week

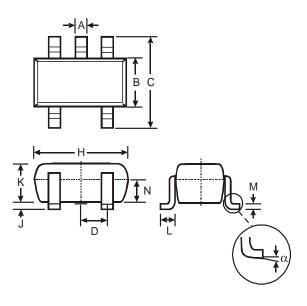
2 3 <u>X</u>: A~Z: Internal code

| Part Number | Package | Identification Code |
|--------------|---------|---------------------|
| 74AHC1G125W5 | SOT25 | YY |
| 74AHC1G125SE | SOT353 | YY |



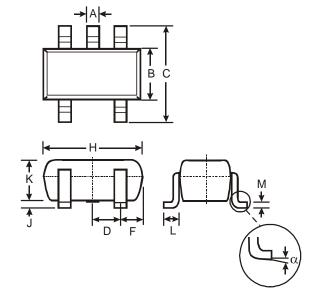
Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT25



| SOT25 | | | | |
|----------------------|-------|------|------|--|
| Dim | Min | Max | Тур | |
| Α | 0.35 | 0.50 | 0.38 | |
| В | 1.50 | 1.70 | 1.60 | |
| O | 2.70 | 3.00 | 2.80 | |
| D | | | 0.95 | |
| Н | 2.90 | 3.10 | 3.00 | |
| 7 | 0.013 | 0.10 | 0.05 | |
| K | 1.00 | 1.30 | 1.10 | |
| L | 0.35 | 0.55 | 0.40 | |
| M | 0.10 | 0.20 | 0.15 | |
| N | 0.70 | 0.80 | 0.75 | |
| α | 0° | 8° | | |
| All Dimensions in mm | | | | |

(2) Package Type: SOT353



| SOT353 | | | | |
|----------------------|----------|------|--|--|
| Dim | Min | Max | | |
| Α | 0.10 | 0.30 | | |
| В | 1.15 | 1.35 | | |
| C | 2.00 | 2.20 | | |
| D | 0.65 Typ | | | |
| F | 0.40 | 0.45 | | |
| Н | 1.80 | 2.20 | | |
| 7 | 0 | 0.10 | | |
| K | 0.90 | 1.00 | | |
| L | 0.25 | 0.40 | | |
| М | 0.10 | 0.22 | | |
| α | 0° | 8° | | |
| All Dimensions in mm | | | | |



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